

DL-7140-201S

Infrared Laser Diode

Features

Wavelength : 785 nm (Typ.)
Low threshold current : Ith = 30 mA (Typ.)
High operating temperature : 70 mW (CW) at 60°C

Applications

• Optical disc system (CD-R)

Absolute Maximum Ratings at Tc=25°C

Parameter		Symbol	Ratings	Unit	
Light Output	CW	Po (CW) 80		mW	
	Pulse 1)	Po (pulse)	85	111 **	
Reverse Voltage	Laser	VR	2	V	
	PD	V K	30	'	
Operating Temperature		Topr	-10 to +60	°C	
Storage Temperature		Tstg	-40 to +85	°C	

¹⁾ Pulse width≤1.0 µs, Duty 50%

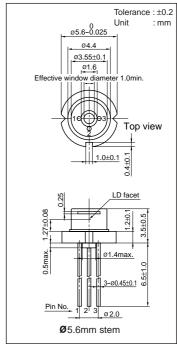
Electrical and Optical Characteristics at Tc=25°C

Paran	neter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshold Curr	rent	Ith	CW	-	30	50	mA
Operating Curr	ent	Iop	Po=70mW	-	100	140	mA
Operating Volta	age	Vop	Po=70mW	-	2.0	2.8	V
Lasing Wavele	ngth	λp	Po=70mW	775	785	800	nm
Beam 2)	Perpendicular	θ⊥	Po=70mW	14	17	20	0
Divergence	Parallel	θ //	Po=70mW	6	8	10	0
Off Axis	Perpendicular	Δθ ⊥	-	-	-	±3	0
Angle	Parallel	Δθ//	-	-	-	±3	0
Differential Ef	ficiency	dPo/dIop	-	0.6	1.0	1.4	mW/mA
Monitoring Ou	tput Current	Im	Po=70mW	0.10	0.25	0.6	mA
Astigmatism		As	Po=70mW	-	-	10	μm

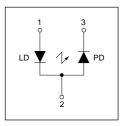
²⁾ Full angle at half maximum

Note: The above product specification are subject to change without notice.

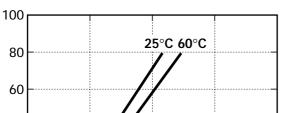
Package Dimensions



Pin Connection



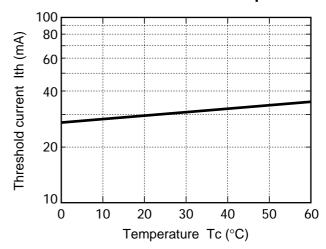
Characteristics



Output power vs. Forward current

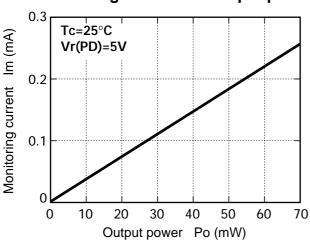
Output power Po (mW) 80 60 40 20 0 0 50 100 150 200

Threshold current vs. Temperature

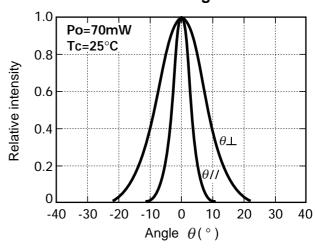




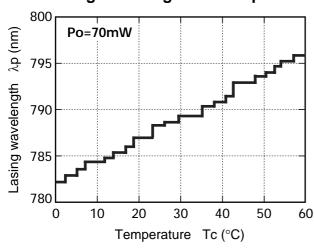
Forward current IF (mA)



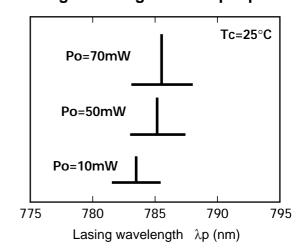
Beam divergence



Lasing wavelength vs. Temperature



Lasing wavelength vs. Output power



Relative intensity



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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

LED Business Unit

5-318, Tachikawa-cho, Tottori City, 680-8634 Japan TEL: +81-857-21-2137 FAX: +81-857-21-2161